

Technical Data Data Sheet N1378, Rev. A

# **MBR1560S SCHOTTKY RECTIFIER**

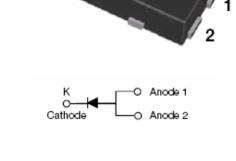
# **Applications:**

- Switching power supply
- Converters
- Free-Wheeling diodes
- Reverse battery protection
- Center tap configuration

### Features:

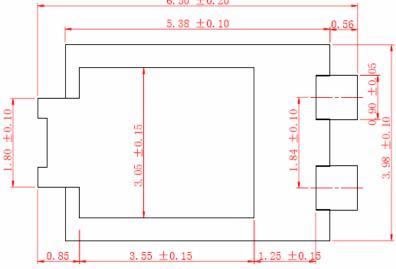
- Designed as Bypass Diodes for Solar Panels
- High Forward Surge Capability
- Ultra Low Forward Voltage Drop
- Excellent High Temperature Stability
- This is a Pb Free Device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request

# Mechanical Dimensions: In mm



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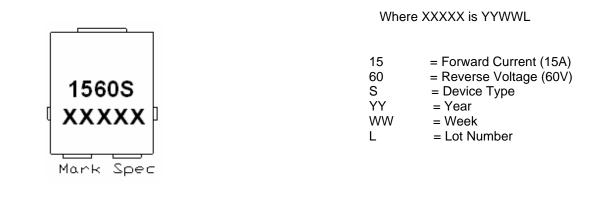
**Green Products** 



Technical Data Data Sheet N1378, Rev. A MBR1560S

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# Marking Diagram:



Cautions: Molding resin Epoxy resin UL:94V-0

# **Ordering Information:**

Device	Package	Shipping
MBR1560S	TO-277B (Pb-Free)	5000pcs/ reel

For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification.

### **Maximum Ratings:**

Characteristics	Symbol	Condition	Max.	Units
Peak Inverse Voltage	V <sub>RWM</sub>	-	60	V
Average Forward Current	I <sub>F(AV)</sub>	50% duty cycle @T <sub>C</sub> =80°C, rectangular wave form	15	A
Peak One Cycle Non- Repetitive Surge Current	I <sub>FSM</sub>	8.3 ms, half Sine pulse	250	А

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# **MBR1560S**

#### Technical Data Data Sheet N1378, Rev. A

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# **Electrical Characteristics:**

Characteristics	Symbol	Condition	Тур.	Max.	Units
Forward Voltage Drop	V <sub>F1</sub>	@ 15A, Pulse, T <sub>J</sub> = 25 °C	0.54	0.59	V
	V <sub>F2</sub>	@ 15A, Pulse, T <sub>J</sub> = 125 °C	0.56	-	V
Reverse Current	I <sub>R1</sub>	$@V_{R} = rated V_{R}$	-	0.2	mA
		T <sub>J</sub> = 25 °C			
	I <sub>R2</sub>	$@V_R = rated V_R$	12	-	mA
		T <sub>J</sub> = 125°C			
Typical Junction	Cj	@V <sub>R</sub> =5.0 V, Tc=25°C	-	850	pF
Capacitance		fsig = 1MHz			

\* Pulse Width < 300µs, Duty Cycle <2%

# Thermal-Mechanical Specifications:

Characteristics	Symbol	Condition	Specification	Units
Junction Temperature	TJ	-	-55 to +150	°C
Storage Temperature	T <sub>stg</sub>	-	-55 to +150	°C
Maximum Thermal Resistance Junction to Soldering Point	$R_{ ext{ heta}JS}$	DC operation	1.5	°C/W
Maximum Thermal Resistance Junction to Case	$R_{ ext{ heta}JC}$	DC operation	2.3	°C/W
Approximate Weight	wt	-	0.08	g
Case Style		TO-277B		



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